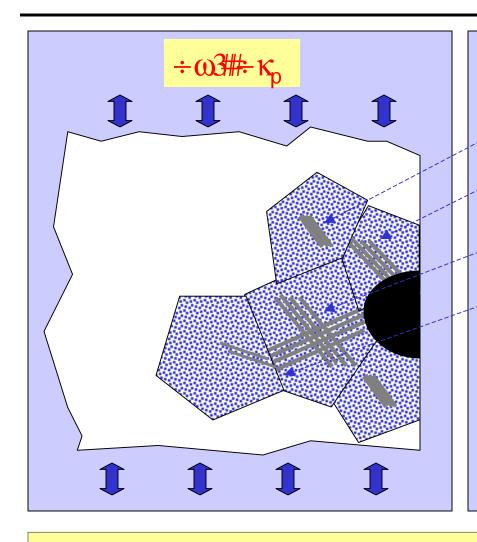


VISION: Predict Microstructure-Sensitive Cyclic ω4κ Curves!



<u>σ4structure Sensitivity of Plasticity</u> <u>in MONOTONIC Loading</u>

Slip Initiation : Source Strengths

Dislocation-Precipitate Interactions

Multislip Work-Hardening within Grain

Grain-Grain Interaction

Bridge with
FATIGUE MODELS
(McDowell, ..)

Cyclic Slip, Slip Localization

Key : Include as many Microstructural & Chemistry Variables as Possible

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OUTLINE

Microstructure Effects Within Grains (v2v')

Using DD SIMULATIONS (S.Rao, T.A.Parthasarathy, D.M.Dimiduk, P.M.Hazzledine)

- PROGRESS: Established a Working Model / Methodology
- CURRENT FOCUS: Connectivity ("Handshakes")

Using FEM (Y-S Choi, T.A.Parthasarathy, D.M.Dimiduk)

Unit Cell Model: Identified Key Issues - Refinements

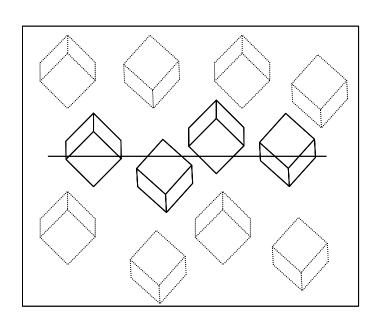
Grain-Grain Interaction

Polycrystal Model: Using DD results

Grain-Defect Interaction

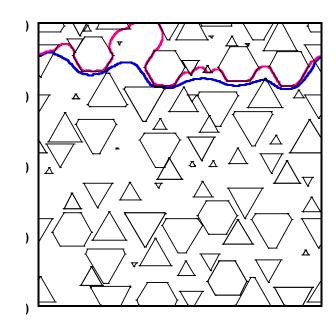


Discrete Dislocation (DD) Simulations



Random Distribution of Cubes in a box

(111) Sections



Spatial Distribution
Varies with Plane of Sectioning



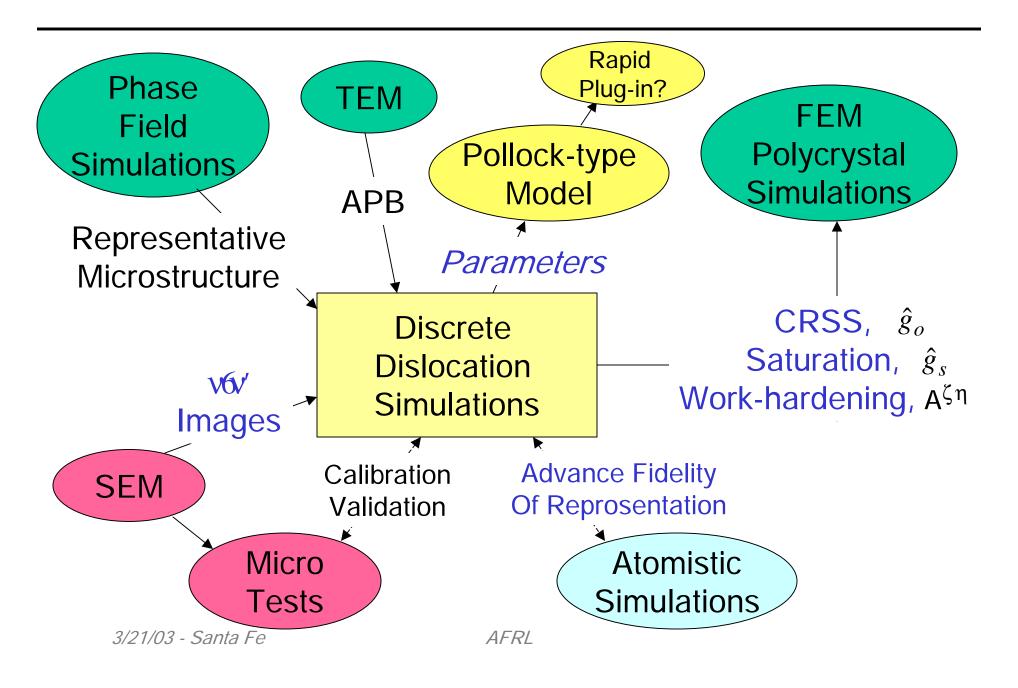
DD: Established 2D Methodology (Low T athermal)

Model	Findings: Parametric Studies	<u>Issues</u>
Precipitate Hardening	Differs from Analytical Model (Reppich) Size & V _f Dep. Reasonable (Expt.) Real Microstructure Simulated	Other Models ? Scatter, ~10% Thresholding
	APB Energy: Primary Factor Friction Stress in v Significant Coherency, Curvature: Negligible	Measure/Calc. Measure?
Multi-Slip WH	3D with cross-slip (Comp. Limited)	Parallel Proc. (CHSSI, AFOSR)

Need "Handshakes" to Meet AIM Goals

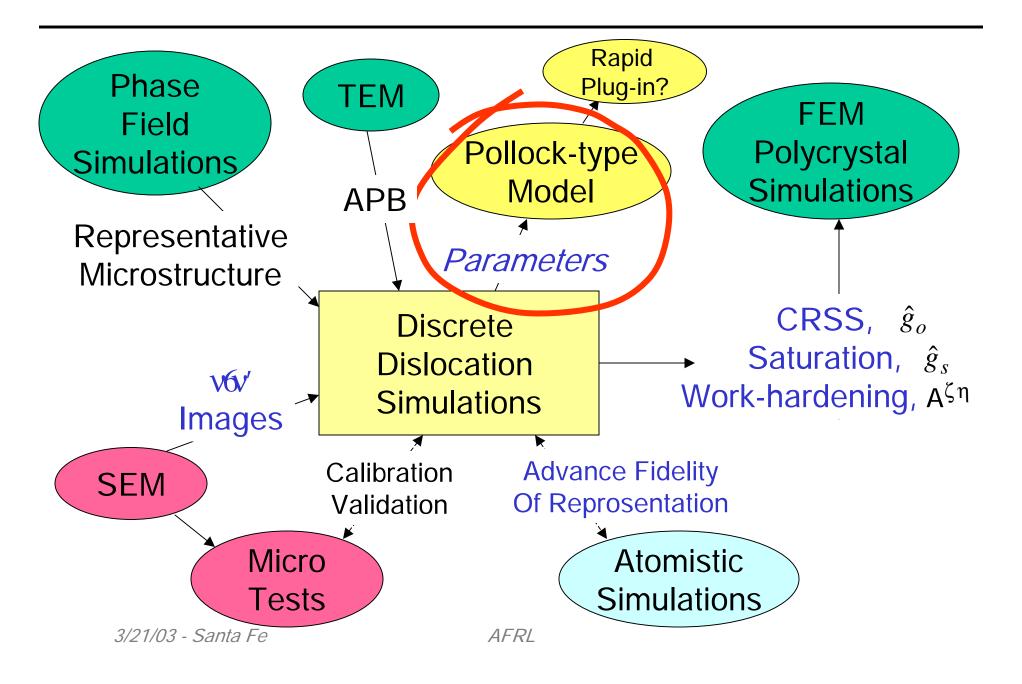


DD: Current Focus - Connectivity ("Handshakes")



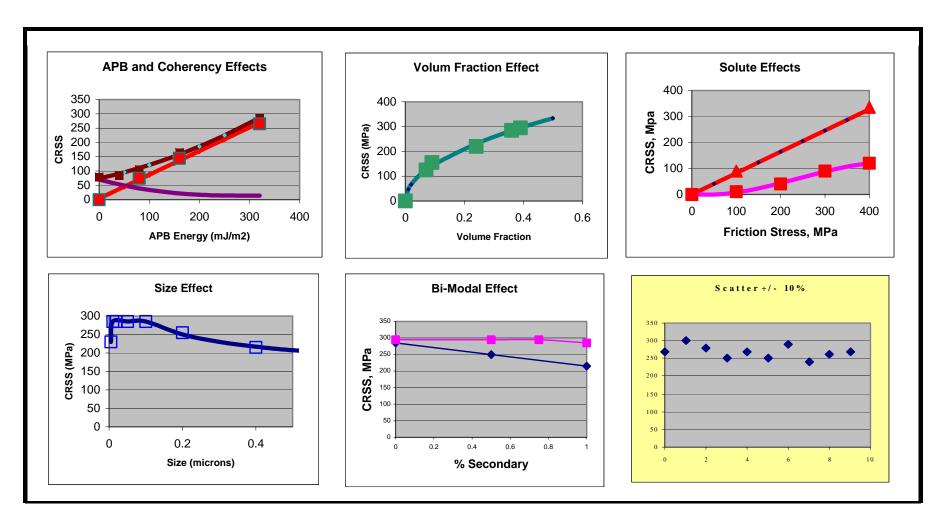


DD: Current Focus - Connectivity ("Handshakes")





DD Parametric Studies



Fits to Parametric Studies => Pollock-type Model

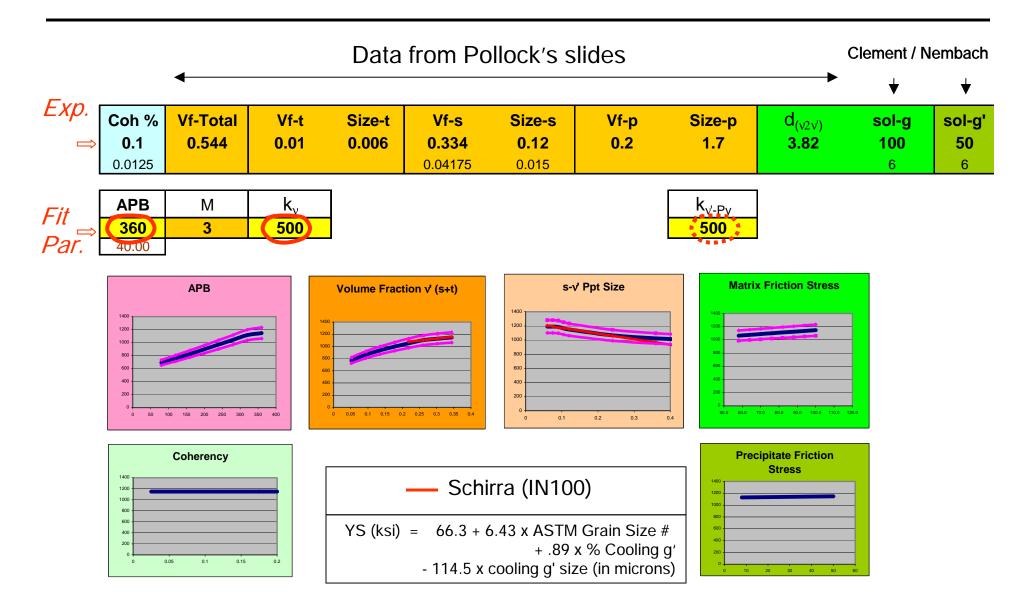


Pollock-type Model: (derived from DD results)

$$\omega_{Y} \mid (14 f_{v'})''(M (CRSS) 2 k_{v2v'} d_{v2v'}^{40.5}) \Leftrightarrow f_{v'} / \vartheta_{0v'} 2 k_{v'} d_{v'}^{40.5})$$

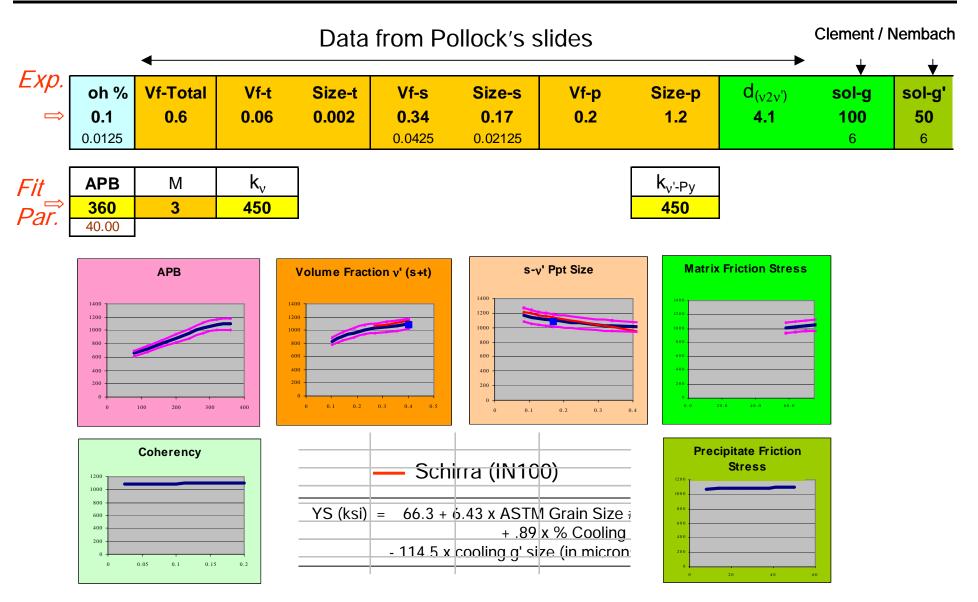


IN 100 - Spreadsheet





Data from Pollock on IN100 (PWA 1100 - ver.3)

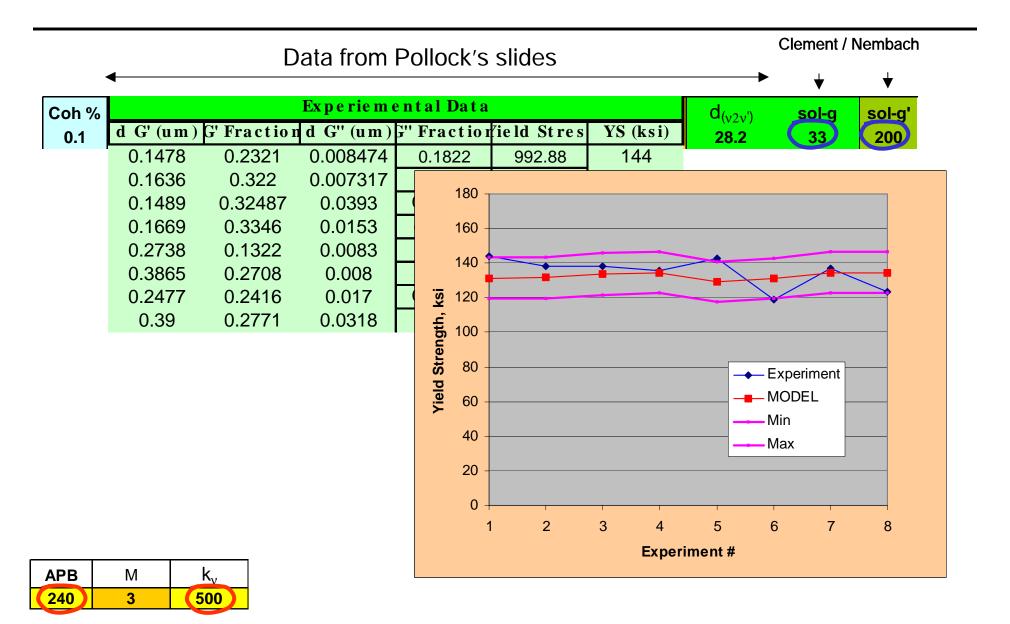


3/21/03 - Santa Fe

AFRL



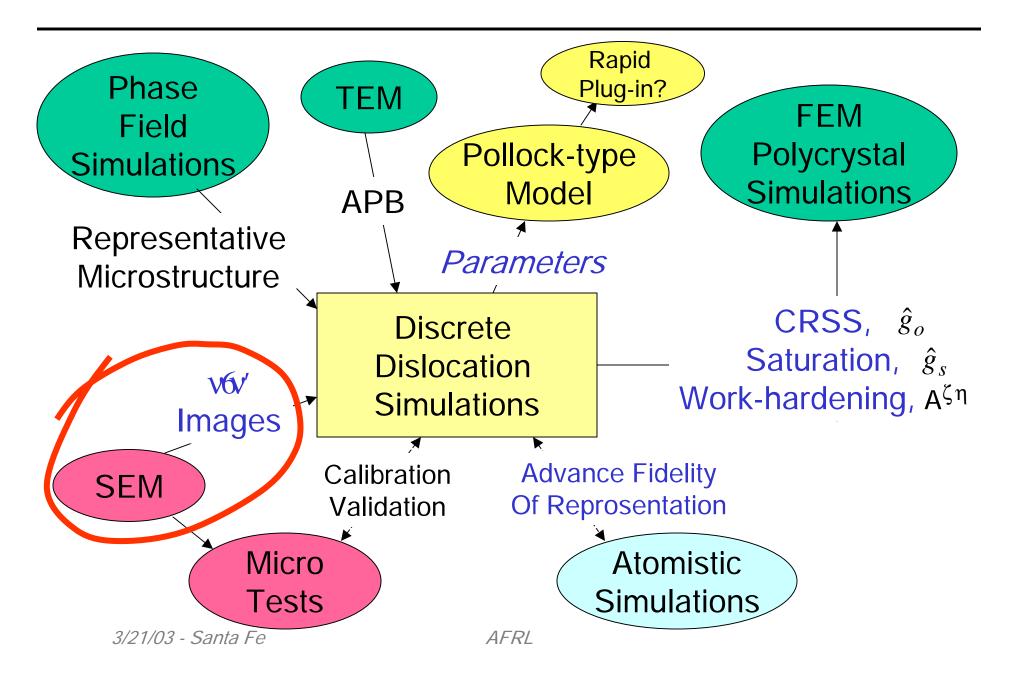
Rene 88 - 1200 F Data (from Pollock's slides)



3/21/03 - Santa Fe

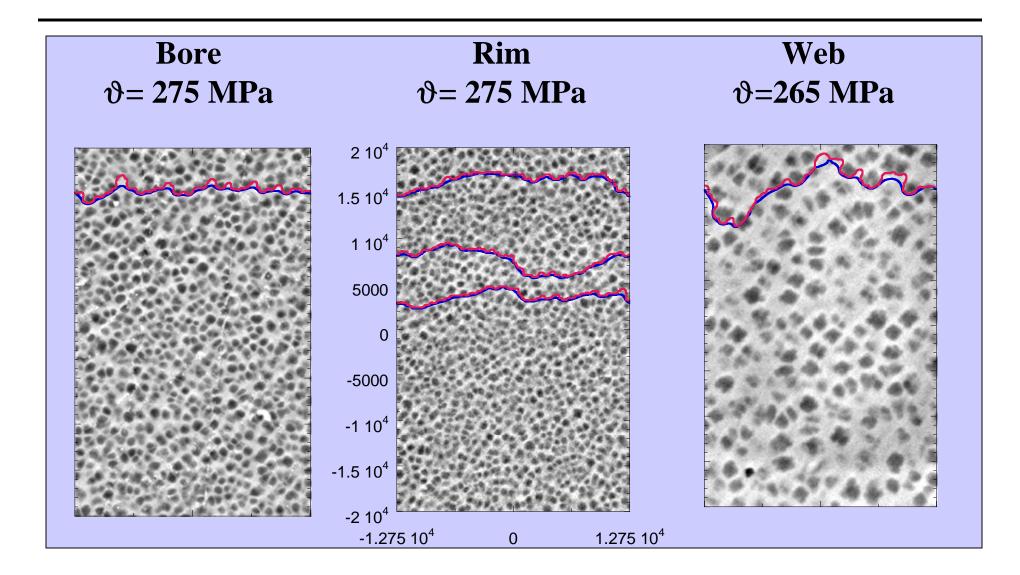


DD: Current Focus - Connectivity ("Handshakes")



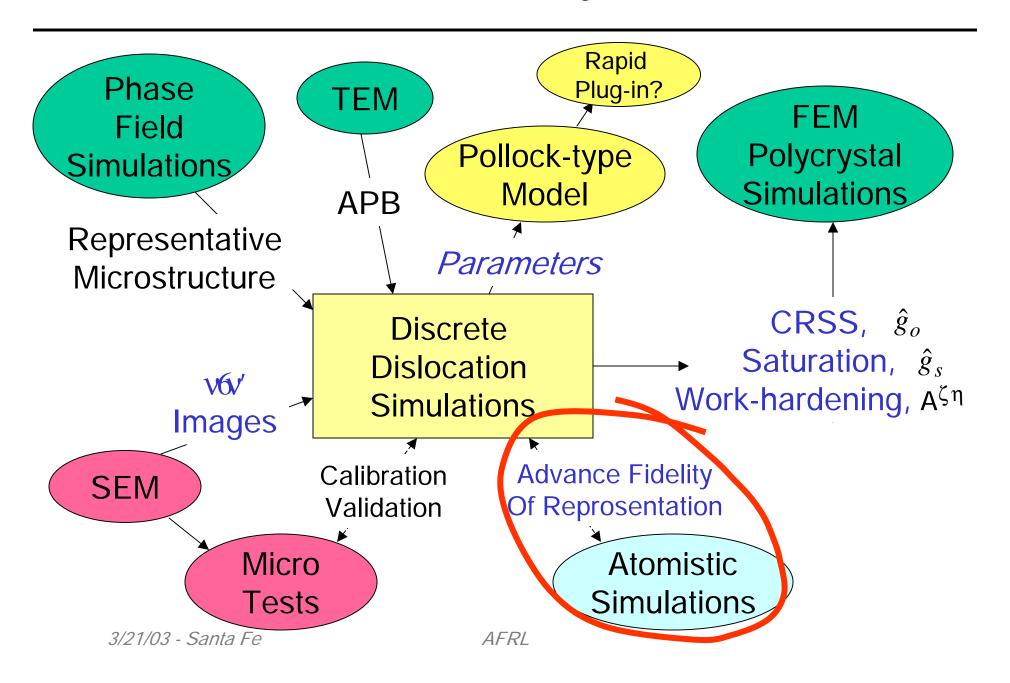


SEM Image -> CRSS



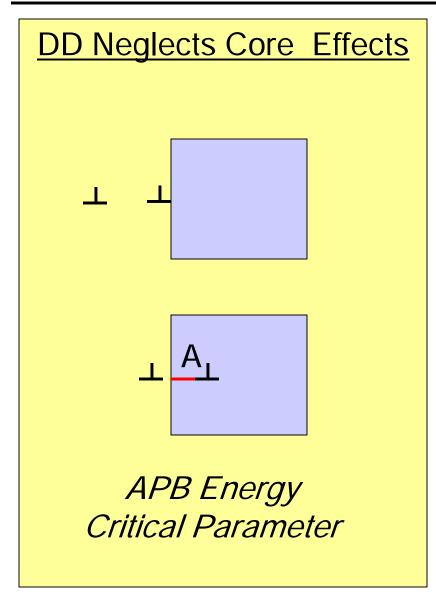


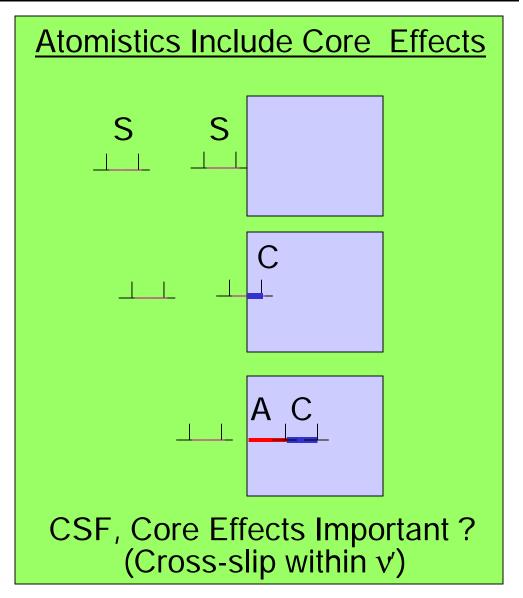
DD: Current Focus - Connectivity ("Handshakes")





Atomistic Simulations -> Refinements of DD







Atomistics Simulation Validation Results

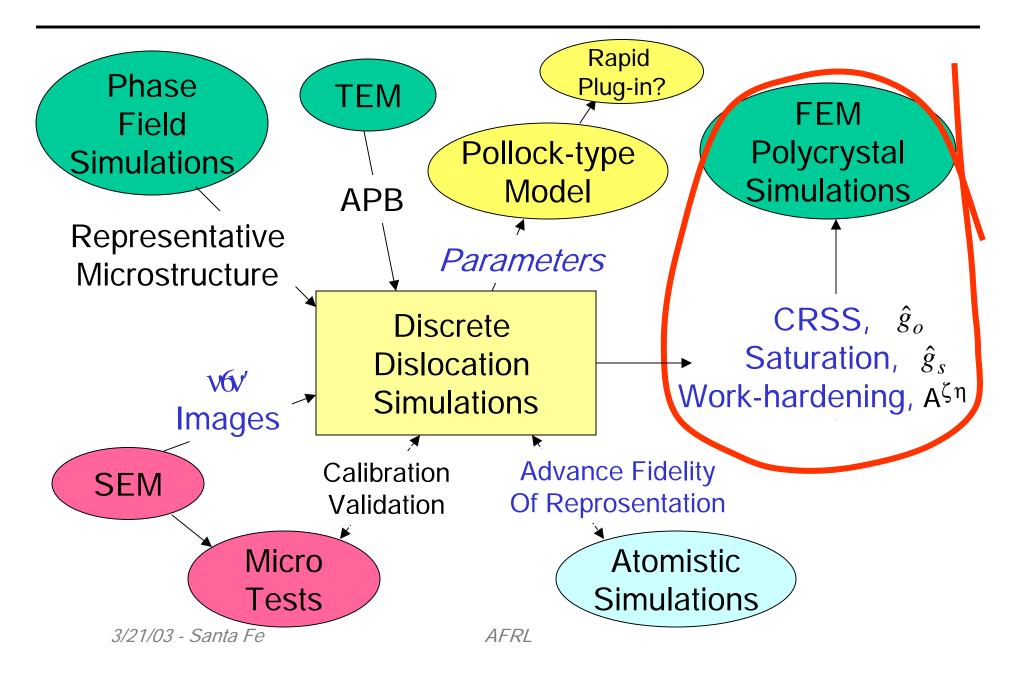
- EAM Potential with APB=140, CSF=120, SF(Ni)=60
- FLAT INTERFACE :

Atomistics

- Stress for first partial to enter: (CSF-SF) / b
- Stress for second partial to enter: (APB) / b
- No diffuse core effect
- <u>DD</u> Max Stress = Stress for 1st DisIn entry = (APB)/b
- => APB Energy Sufficient, if APB (CSF-SF)

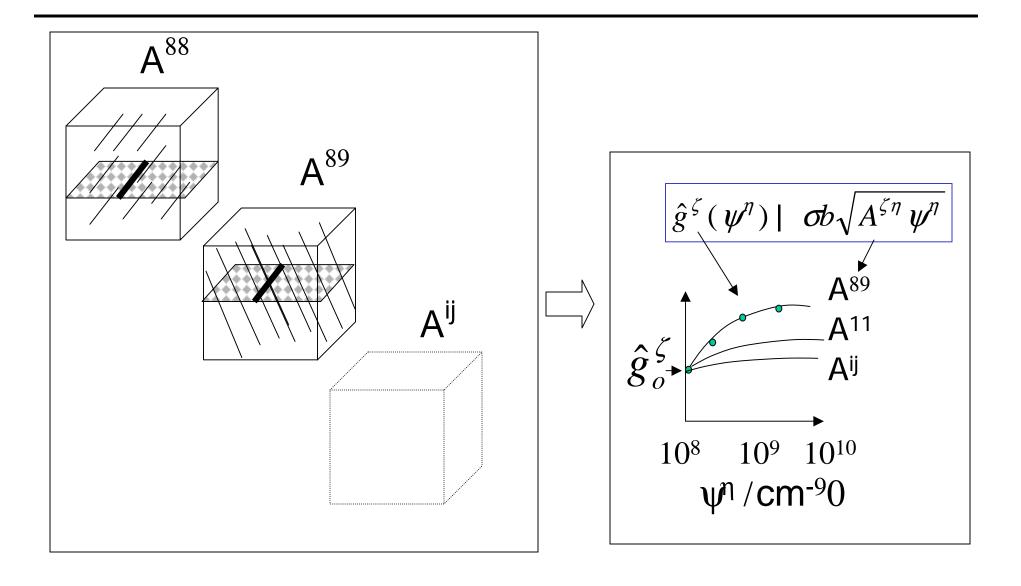


DD: Current Focus - Connectivity ("Handshakes")





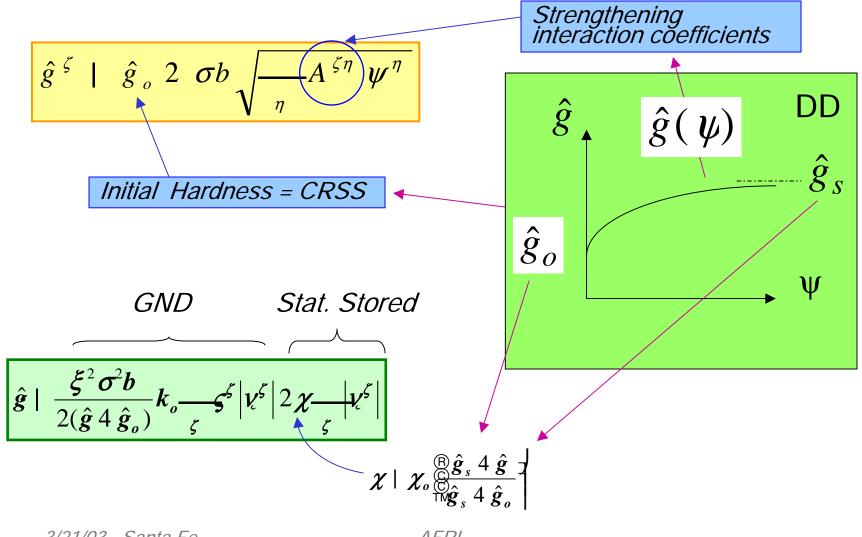
DD -> FEM Handoffs





DD -> FEM Handoffs

γ Forest Obstacle Model (Franciosi, 1985)



3/21/03 - Santa Fe

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Grain-Grain Interaction

Polycrystal Model: Using DD results

Grain-Defect Interaction



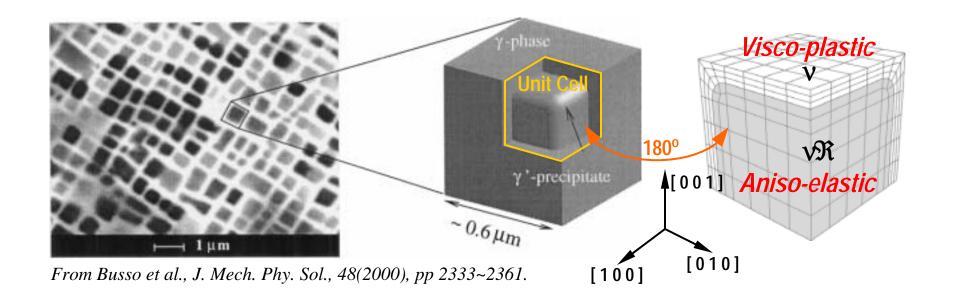
FEM: Unit Cell Model (Single Grain)

- Evaluated Unit Cell Approach using A-B Formalism
 - Yield Point -> determined by geometrical constraint (different mechanism than DD)
 - W-H beyond Yield -> strain-gradient term dominant

Refinement : Relaxation of Elastic v' (using DD results)



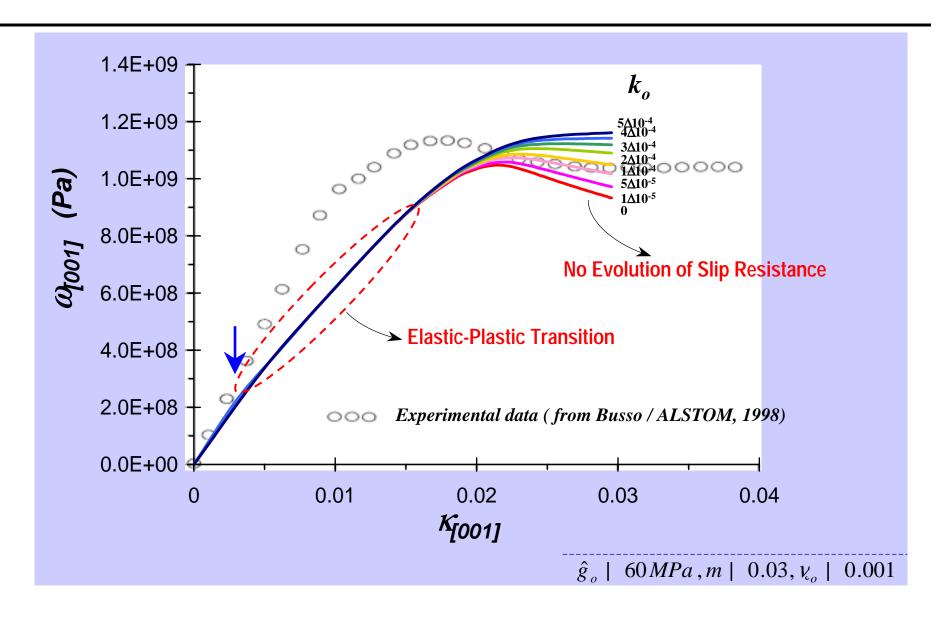
FE Simulation of (v+v') : Unit Cell Approach



$$|v^{\zeta}| |v_{o} \operatorname{sgn}(v^{\zeta})| \left| \frac{v^{\zeta}}{\hat{g}^{\zeta}} \right|^{1/m} \quad \text{with} \quad |\hat{g}| \frac{\xi^{2} \sigma^{2} b}{2(\hat{g} + \hat{g}_{o})} k_{o} \frac{\zeta^{\zeta}}{\zeta} |v^{\zeta}| \quad \begin{array}{c} \operatorname{Only} \zeta^{\zeta} (GND) \\ \operatorname{contribution} \text{ to slip} \\ \operatorname{resistance}. \end{array}$$

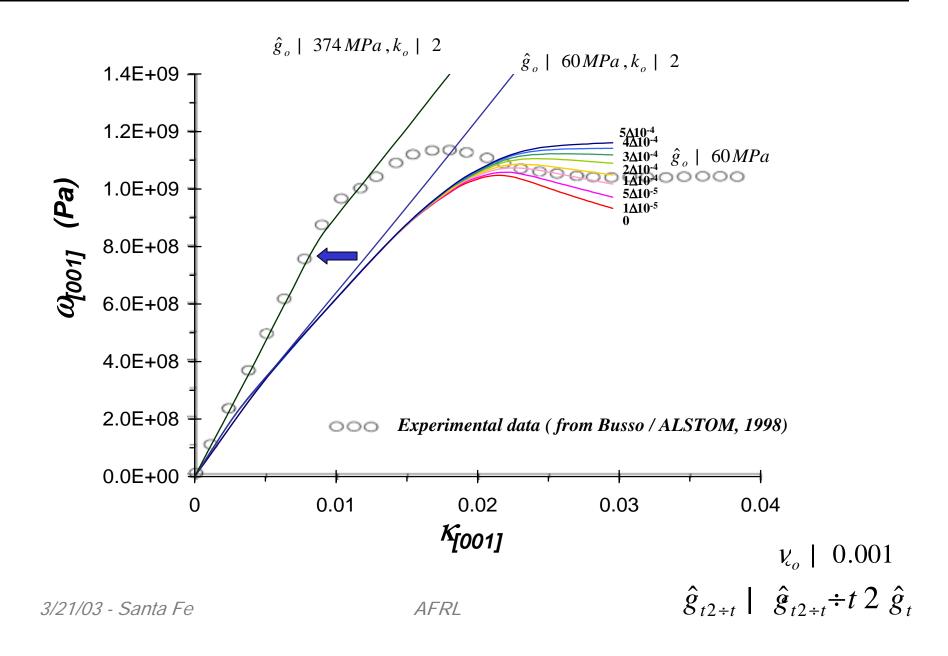


Effect of Strain-Gradient Parameter: k_o





Effect of \hat{g}_o

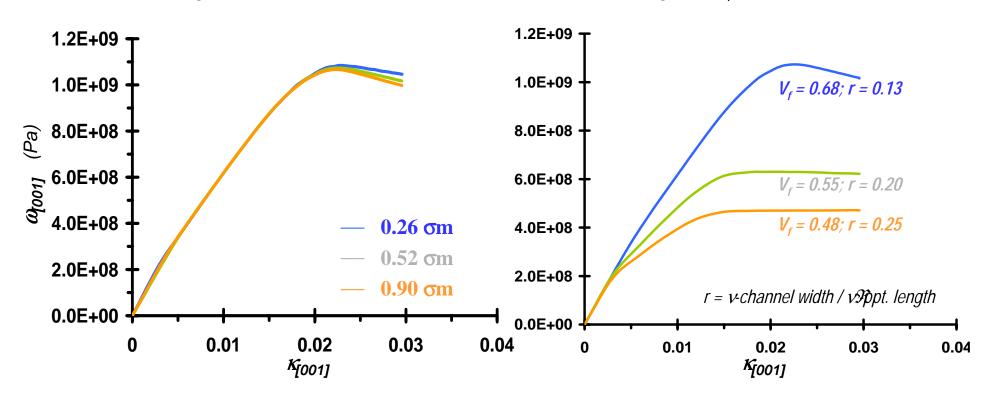




Length Scale Effects: V Size, V_f

- \triangleright Constant $\sqrt{3}$ ppt. $V_f = 68\%$
- > Change vℜize (v-channel width)

- \triangleright Constant $\sqrt{\Re}$ ize = 0.52 σm
- \triangleright Change $\sqrt{\mathcal{W}}_f$ (v-channel width)

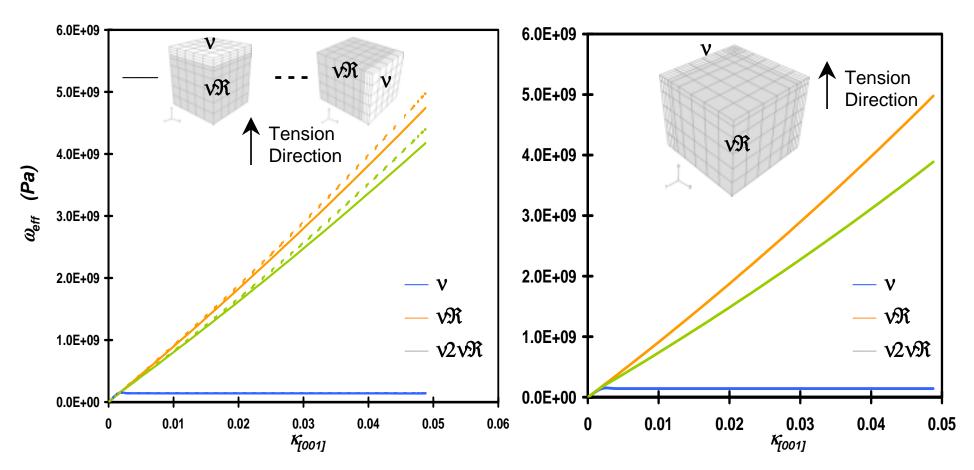


 $\hat{g}_{o} \mid 60MPa, m \mid 0.03, v_{o} \mid 0.001, k_{o} \mid 5\Delta 10^{45}$ 3/21/03 - Santa Fe



Effect of VV30 Geometry

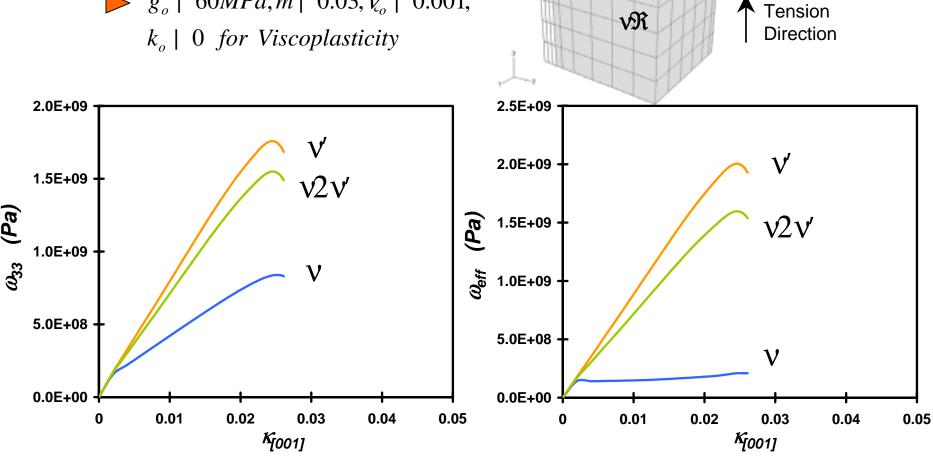
- ► Elastic √92 Elasto-viscoplastic ν
- $\hat{g}_o \mid 60MPa, m \mid 0.03, v_o \mid 0.001, k_o \mid 0 \text{ for Viscoplasticity}$

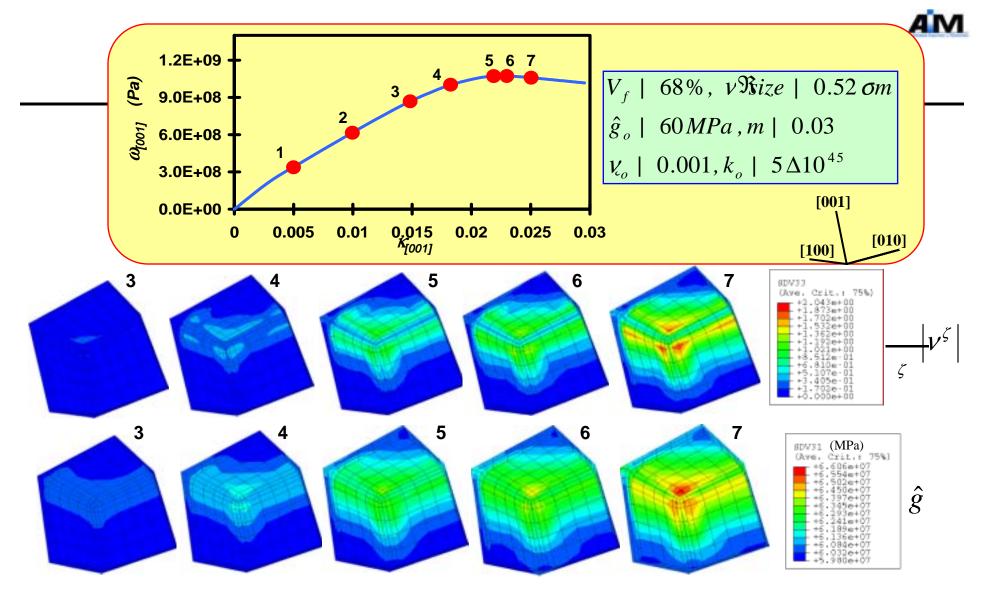




Effect of $\sqrt{3D}$ Geometry

- Elastic v92 Elasto-viscoplastic v
- $\hat{g}_{o} \mid 60MPa, m \mid 0.03, v_{o} \mid 0.001,$





- The onset of softening accompanied by the massive shears localized along the edges and the corners in the \sqrt{N} interfaces
 - ♥ Break down of geometric (kinematic) constraints
 - 3€1/Need to compare with experimental observations at this particular T-range



FEM: Unit Cell Model (Single Grain)

- Evaluated Unit Cell Approach using A-B Formalism
 - Yield Point -> determined by geometrical constraint
 captures V_f Effect
 - W-H beyond Yield -> strain-gradient term dominant
 captures size effect during work-hardening
- Refinement : Allow Plasticity in v' (using DD results)
 - DD captures APB cutting,
 - FEM captures Geometrical Constraint effect and Work Hardening



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Grain-Grain Interaction

Polycrystal Model: Using DD results

Grain-Defect Interaction



FEM: Polycrystal Model

- FY 2003 Goal : Combine DD with FEM to Build 1st gen. (v2v') Polycrystal model
 - Wigner-Seitz Cell (Beaudoin) (144 grains, 12 el/gr)
 - Use DD results for g_o and A_{ii}
 - A-B model for Strain-gradient Terms
- Beyond FY2003
 - Build/Borrow v' const. Law to Model IN100 type alloy
 - Real Image 3D Polycrystal Models
 - Adaptive Meshing of Realistic Microstructures

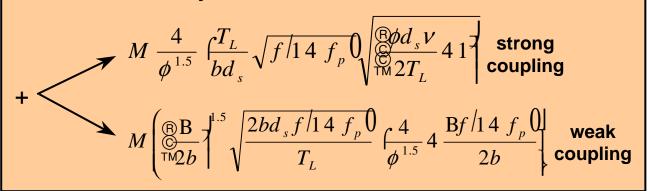


Building Bridges: Inputs for Pollock-type Model

Needs Development Within Atomistics

$$\omega_{y}/C_{i}, T, \kappa, \kappa, \dots 0 | f_{v} \underbrace{ \frac{dC_{o}}{dC_{i}} \sqrt{C_{i}}}_{\text{TM}} + Mf_{t} \underbrace{ \frac{B_{APB}}{b}}_{\text{TM}}$$

Obtain by Dislocation Kinetics Simulation



Obtain by FEM Simulation of Grain Distribution Effects

+
$$\int 14 f_p \mathcal{O}_{y}^{\nu} \frac{1}{\sqrt{d_{\nu}}} + f_p \left(\omega / T \mathcal{O}_{Ni_3Al} 2 \frac{\mathbb{R} dc}{\mathbb{R} dC_i} C_i \right) + \int_p k_y^{\nu \Re} \frac{1}{\sqrt{d_{\nu \Re}}}$$



Building Bridges

<u>TO</u>

Inputs for Pollock-type Model
 3-6 mo.

Fatigue Models (McDowell,..)
 1-2 yrs

<u>FROM</u>

v' Constitutive Laws (Parks, Cuitino/Ortiz, ...)
 3-6 mo.

• 3D Voronoi Meshing (Parks, Gosh, ..) 3-6 mo.